

KEY ROLE OF THE RESIN LAYER THICKNESS IN THE LABILITY OF COMPLEXES MEASURED BY DGT

SUPPORTING INFORMATION

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Journal: Environmental Science and Technology

Date: 27-04-2011

Document with 25 pages, 7 figures and 1 Table

Supplementary information available:

Section 1: Numerical Simulation of a DGT Sensor.

Section 2: Concentration profiles in a DGT experiment.

Section 3: Experimental Section.

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Section 5.- Formulation of the Cd-NTA speciation in a DGT sensor as a system with only one complex and ligand species.

Section 6.- Parameter values of all the figures of the manuscript

1.- Numerical Simulation of a DGT Sensor

1.1.- The Model

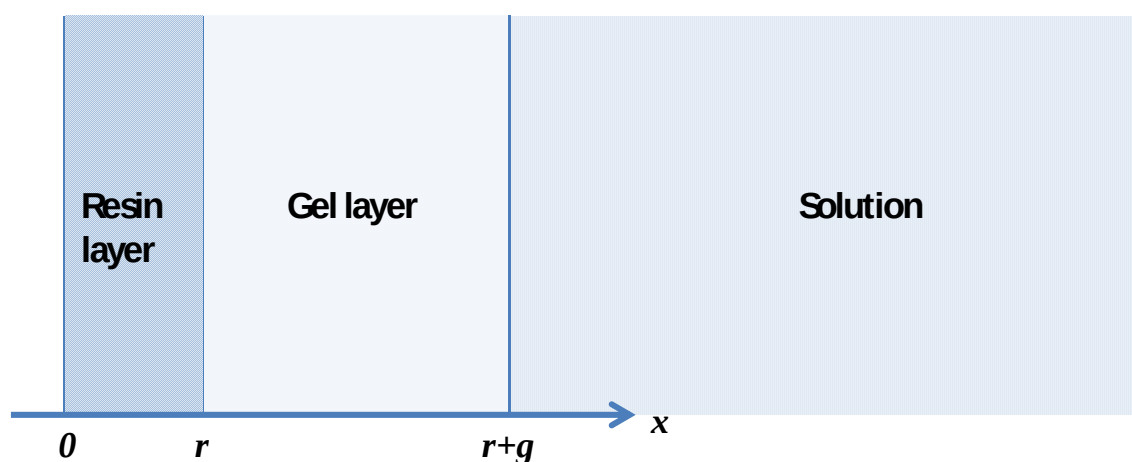


Figure SI-1. Schematic representation of a DGT device.

The model formulation coincides with that of (Lehto et al. 2006) and (Tusseau-Vuillemin et al. 2003).

Let D_i and $D_{i,R}$ stand for the diffusion coefficients of species i in the diffusive gel or in the resin domain, respectively and let c_i stand for the concentration of species i at a given spatial position x and time t . Total concentrations are denoted as $c_{T,i}$.

. The transport equations for the different species can be written as:

- For the metal in the gel layer and in the resin layer:

$$\frac{\partial c_M}{\partial t} = D_{M,R} \frac{\partial^2 c_M}{\partial x^2} - k_a c_M c_L + k_d c_{ML} - k_{a,R} c_M c_R + k_{d,R} c_{MR}, \quad \text{if } 0 < x < r \quad (\text{SI-1})$$

$$\frac{\partial c_M}{\partial t} = D_M \frac{\partial^2 c_M}{\partial x^2} - k_a c_M c_L + k_d c_{ML}, \quad \text{if } r < x < r + g \quad (\text{SI-2})$$

- For the ligand:

$$\frac{\partial c_L}{\partial t} = \left\{ \begin{array}{l} D_{L,R} \\ D_L \end{array} \right\} \frac{\partial^2 c_L}{\partial x^2} + k_a c_M c_L - k_d c_{ML}, \quad \text{if } 0 < x < r + g \quad (\text{SI-3})$$

where the curly bracket indicates that $D_{L,R}$ applies when $0 < x < r$ and D_L applies when $r < x < r + g$

- For the complex (assuming the same diffusion coefficient for complex and ligand):

$$\frac{\partial c_{ML}}{\partial t} = \left\{ \begin{array}{l} D_{L,R} \\ D_L \end{array} \right\} \frac{\partial^2 c_{ML}}{\partial x^2} + k_a c_M c_L - k_d c_{ML}, \quad \text{if } 0 < x < r + g \quad (\text{SI-4})$$

- For the resin sites free (R) or occupied (MR):

$$\frac{\partial c_R}{\partial t} = -k_{a,R} c_M c_R + k_{d,R} c_{MR}, \quad \text{if } 0 < x < r \quad (\text{SI-5})$$

$$\frac{\partial c_{MR}}{\partial t} = +k_{a,R} c_M c_R - k_{d,R} c_{MR}, \quad \text{if } 0 < x < r \quad (\text{SI-6})$$

There are no resin sites in the gel domain: $c_R(x, t) = c_{MR}(x, t) = 0$ for $r < x < r + g$.

Initial conditions correspond to the absence of metal and ligand in the sensor:

$$c_M(x,0) = c_L(x,0) = c_{ML}(x,0) = 0, \quad \text{if } 0 < x < r + g \quad (\text{SI-7})$$

$$c_{MR}(x,0) = 0 \quad \text{if } 0 < x < r \quad (\text{SI-8})$$

$$c_R(x,0) = c_{T,R} \quad \text{if } 0 < x < r \quad (\text{SI-9})$$

where $c_{T,R}$ denotes the total concentration of resin sites (free or occupied).

Boundary conditions at $x = r + g$ correspond to bulk concentrations:

$$c_M(r + g, t) = c_M^*, \quad c_L(r + g, t) = c_L^*, \quad c_{ML}(r + g, t) = c_{ML}^* \quad (\text{SI-10})$$

Boundary conditions at $x = r$:

at the gel-resin interface $c_M(x, t)$, $c_L(x, t)$, and $c_{ML}(x, t)$ and their fluxes must be continuous, that is

$$c_M(r^-, t) = c_M(r^+, t), \quad c_L(r^-, t) = c_L(r^+, t), \quad c_{ML}(r^-, t) = c_{ML}(r^+, t) \quad \text{and} \quad (\text{SI-11})$$

$$D_{M,R} \left. \frac{\partial c_M}{\partial x} \right|_{r^-} = D_M \left. \frac{\partial c_M}{\partial x} \right|_{r^+}, \quad D_{L,R} \left. \frac{\partial c_L}{\partial x} \right|_{r^-} = D_L \left. \frac{\partial c_L}{\partial x} \right|_{r^+}, \quad D_{L,R} \left. \frac{\partial c_{ML}}{\partial x} \right|_{r^-} = D_L \left. \frac{\partial c_{ML}}{\partial x} \right|_{r^+} \quad (\text{SI-12})$$

The continuity of the concentrations indicates that no Donnan effects are considered, so that charge effects of the resin are screened by the supporting electrolyte.

Boundary conditions at $x = 0$ stem from non-flux conditions:

$$\left. \frac{\partial c_M}{\partial x} \right|_{x=0} = \left. \frac{\partial c_L}{\partial x} \right|_{x=0} = \left. \frac{\partial c_{ML}}{\partial x} \right|_{x=0} = 0. \quad (\text{SI-13})$$

Eqns. (SI-1)-(SI-6) with the initial conditions (SI-7 to SI-9) and boundary value problem (SI-10-SI-13) form a system of equations for $c_M(x, t)$, $c_L(x, t)$, $c_{ML}(x, t)$, $c_R(x, t)$ and $c_{MR}(x, t)$.

It could be useful to introduce the total ligand concentration, $c_{T,L}$. Adding equations

(SI-3) and (SI-4), the transport equation for $c_{T,L}$ becomes:

$$\frac{\partial c_{T,L}}{\partial t} = \begin{cases} D_{L,R} \\ D_L \end{cases} \frac{\partial^2 c_{T,L}}{\partial x^2}, \quad \text{if } \begin{cases} 0 < x < r \\ r < x < r + g \end{cases}, \quad (\text{SI-14})$$

with initial and boundary conditions given by:

$$c_{T,L}(x,0) = 0, \quad \left. \frac{\partial c_{T,L}}{\partial x} \right|_{x=0} = 0, \quad c_{T,L}(r+g,t) = c_{T,L}^* \quad \text{and} \quad (\text{SI-15})$$

$$c_{T,L}(r^-,t) = c_{T,L}(r^+,t), \quad D_{L,R} \left. \frac{\partial c_{T,L}}{\partial x} \right|_{r^-} = D_L \left. \frac{\partial c_{T,L}}{\partial x} \right|_{r^+} \quad (\text{SI-16})$$

Additionally, we can introduce the total resin concentration:

$$c_R(x,t) + c_{MR}(x,t) = c_{T,R} \quad (\text{SI-17})$$

The addition of Eqs. (SI-5) and (SI-6) indicates, as physically expected, that $c_{T,R}$ is time independent. Thus the finding of $c_M(x,t)$, $c_L(x,t)$, $c_{ML}(x,t)$, $c_R(x,t)$ and $c_{MR}(x,t)$ can be reduced to the finding of $c_M(x,t)$, $c_L(x,t)$, $c_{T,L}(x,t)$, and $c_R(x,t)$ in the domain $0 < x < r+g$.

1.2.- Dimensionless Reformulation

Let us reformulate the problem in terms of dimensionless functions and normalized variables.

Let z be the spatial normalized variable. Its relationship with x and with its derivatives is:

$$z = \frac{x}{\sqrt{D_M}} \rightarrow \frac{\partial^2}{\partial z^2} = \frac{1}{D_M} \frac{\partial^2}{\partial x^2} \quad (\text{SI-18})$$

Then

$$r^* = \frac{r}{\sqrt{D_M}}, \quad g^* = \frac{r+g}{\sqrt{D_M}} \quad (\text{SI-19})$$

The dimensionless diffusion coefficients:

$$d_i = \frac{D_i}{D_M}, \quad i = M, R; L; L, R. \quad (\text{SI-20})$$

The dimensionless concentrations:

$$q_M = \frac{c_M}{c_M^*}, \quad q_L = \frac{c_L}{c_L^*}, \quad q_{TL} = \frac{c_{T,L}}{c_{T,L}^*}, \quad q_M = \frac{c_R}{c_{T,R}^*} \quad (\text{SI-21})$$

With these definitions, the transport equations become:

- For the dimensionless metal:

$$\frac{\partial q_M}{\partial t} = d_{M,R} \frac{\partial^2 q_M}{\partial z^2} - k_a c_L^* q_M q_L + k_d \left(\frac{c_{T,L}^*}{c_M^*} q_{T,L} - \frac{c_L^*}{c_M^*} q_L \right) - k_{a,R} c_{T,R}^* q_M q_R + \frac{k_{d,R} c_{T,R}^*}{c_M^*} (1 - q_R), \quad (\text{SI-22})$$

for $0 < z < r^*$, and

$$\frac{\partial q_M}{\partial t} = \frac{\partial^2 q_M}{\partial z^2} - k_a c_L^* q_M q_L + k_d \left(\frac{c_{T,L}^*}{c_M^*} q_{T,L} - \frac{c_L^*}{c_M^*} q_L \right), \quad \text{for } r^* < z < g^* \quad (\text{SI-23})$$

with initial and boundary conditions:

$$q_M(z, 0) = 0, \quad \left. \frac{\partial q_M}{\partial z} \right|_{z=0} = 0, \quad q_M(g^*, t) = 1, \quad (\text{SI-24})$$

$$q_M(r^{*-}, t) = q_M(r^{*+}, t), \quad d_{M,R} \left. \frac{\partial q_M}{\partial z} \right|_{z=r^{*-}} = \left. \frac{\partial q_M}{\partial z} \right|_{z=r^{*+}}. \quad (\text{SI-25})$$

- Equations for the dimensionless ligand:

$$\frac{\partial q_L}{\partial t} = \left\{ \frac{d_{L,R}}{d_L} \right\} \frac{\partial^2 q_L}{\partial z^2} - k_a c_M^* q_M q_L + k_d \left(\frac{c_{T,L}^*}{c_L^*} q_{T,L} - q_L \right), \quad (\text{SI-26})$$

$$q_L(z, 0) = 0, \quad \left. \frac{\partial q_L}{\partial z} \right|_{z=0} = 0, \quad q_L(g^*, t) = 1, \quad (\text{SI-27})$$

$$q_L(r^{*-}, t) = q_L(r^{*+}, t), \quad \frac{d_{L,R}}{d_L} \left. \frac{\partial q_L}{\partial z} \right|_{z=r^{*-}} = \left. \frac{\partial q_L}{\partial z} \right|_{z=r^{*+}}. \quad (\text{SI-28})$$

- Equations for the dimensionless total ligand:

$$\frac{\partial q_{T,L}}{\partial t} = \left\{ \frac{d_{L,R}}{d_L} \right\} \frac{\partial^2 q_{T,L}}{\partial z^2}, \quad (\text{SI-29})$$

$$q_{T,L}(z, 0) = 0, \quad \left. \frac{\partial q_{T,L}}{\partial z} \right|_{z=0} = 0, \quad q_{T,L}(g^*, t) = 1, \quad (\text{SI-30})$$

$$q_{T,L}(r^{*-}, t) = q_{T,L}(r^{*+}, t), \quad \frac{d_{L,R}}{d_L} \left. \frac{\partial q_{T,L}}{\partial z} \right|_{z=r^{*-}} = \left. \frac{\partial q_{T,L}}{\partial z} \right|_{z=r^{*+}}. \quad (\text{SI-31})$$

- Equation for the dimensionless free resin concentration:

$$\frac{\partial q_R}{\partial t} = -k_{a,R} c_M^* q_M q_R + k_{d,R} (1 - q_R), \quad \text{if } 0 < z < r^*, \quad (\text{SI-32})$$

with initial condition $q_R(z, 0) = 1$.

1.3.- Discretization

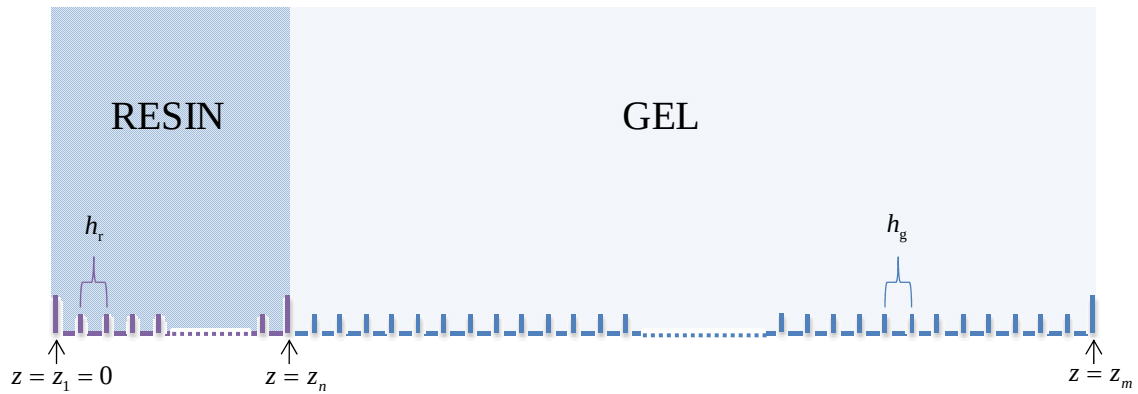


Figure SI-2. Schematic representation of spatial grid.

The resin layer domain will be divided into $n-1$ equal parts of length $h_r = \frac{r}{n-1}$. The

gel domain will be divided into $m-n-1$ parts of length $h_g = \frac{g}{m-n-1}$ as shown in figure

SI-2. The partial differential equations are discretized using spatial finite differences and a temporal Inverse-Euler scheme with constant Δt .

1.3.1.- Resin sites concentration

The discretization of equation (SI-32) becomes:

$$q_R(z, t + \Delta t) - q_R(z, t) = -\Delta t k_{a,R} c_M^* q_M(z, t + \Delta t) q_R(z, t + \Delta t) + \Delta t k_{d,R} (1 - q_R(z, t + \Delta t)) \quad (\text{SI-33})$$

which leads to:

$$q_R(z, t + \Delta t) = \frac{q_R(z, t) + \Delta t k_{d,R}}{1 + \Delta t k_{a,R} c_M^* q_M(z, t + \Delta t) + \Delta t k_{d,R}} \quad (\text{SI-34})$$

1.3.2.- Total ligand concentration

Although equation (SI-29) could be analytically solved, its computational cost is greater than the cost of its numerical solution. The discretized form of equation (SI-29) is:

$$q_{T,L}(z, t + \Delta t) - q_{T,L}(z, t) = \begin{Bmatrix} \alpha_L \\ \alpha_{L,R} \end{Bmatrix} \left[q_{T,L}(z + h_i, t + \Delta t) - 2q_{T,L}(z, t + \Delta t) + q_{T,L}(z - h_i, t + \Delta t) \right] \quad (\text{SI-35})$$

Where h_i is equal to h_r or h_g depending on the domain, $\alpha_L = d_L \Delta t / h_g^2$ and

$$\alpha_{L,R} = d_{L,R} \Delta t / h_r^2.$$

Equation (SI-35) can be rewritten as:

$$-\begin{Bmatrix} \alpha_L \\ \alpha_{L,R} \end{Bmatrix} q_{T,L}(z - h_i, t + \Delta t) + \left(1 + 2 \begin{Bmatrix} \alpha_L \\ \alpha_{L,R} \end{Bmatrix} \right) q_{T,L}(z, t + \Delta t) - \begin{Bmatrix} \alpha_{L,R} \\ \alpha_L \end{Bmatrix} q_{T,L}(z + h_i, t + \Delta t) = q_{T,L}(z, t). \quad (\text{SI-36})$$

which enables the equation system for $q_{T,L}(z_i, t + \Delta t)$ to be built:

- For z_1 , the equation for $q_{T,L}(z_1, t + \Delta t)$ is obtained from equation (SI-30), corresponding to the null flux condition at the origin,

$$q_{T,L}(z_2, t + \Delta t) - q_{T,L}(z_1, t + \Delta t) = 0. \quad (\text{SI-37})$$

- For $j = 2$ to $n - 1$, the equations are obtained from (SI-36) considering the resin layer domain:

$$-\alpha_{L,R} q_{T,L}(z_j - h_r, t + \Delta t) + (1 + 2\alpha_{L,R}) q_{T,L}(z_j, t + \Delta t) - \alpha_{L,R} q_{T,L}(z_j + h_r, t + \Delta t) = q_{T,L}(z_j, t)$$

(SI-38)

- At z_n , that is $z = r^*$, the equation is obtained from the boundary condition (SI-

31):

$$\frac{d_{L,R}}{d_L} \frac{q_{T,L}(z_n, t + \Delta t) - q_{T,L}(z_{n-1}, t + \Delta t)}{h_r} = \frac{q_{T,L}(z_{n+1}, t + \Delta t) - q_{T,L}(z_n, t + \Delta t)}{h_g}, \quad (\text{SI-39})$$

which can be rewritten as

$$-\sigma q_{T,L}(z_{n-1}, t + \Delta t) + (\sigma + 1)q_{T,L}(z_n, t + \Delta t) - q_{T,L}(z_{n+1}, t + \Delta t) = 0 \quad (\text{SI-40})$$

where $\sigma = \frac{h_g d_{LR}}{h_r d_L}$

- For $j = n + 1$ to $m - 1$, we are in the gel domain and the equations for $q_{T,L}(z_j, t + \Delta t)$ are obtained from (SI-36):

$$-\alpha_L q_{T,L}(z_j - h_g, t + \Delta t) + (1 + 2\alpha_L)q_{T,L}(z_j, t + \Delta t) - \alpha_L q_{T,L}(z_j + h_g, t + \Delta t) = q_{T,L}(z_j, t) \quad (\text{SI-41})$$

- Finally, for $z = g^*$ the equation is obtained from condition in (SI-30):

$$q_{T,L}(g^*, t + \Delta t) = 1 \quad (\text{SI-42})$$

1.3.3.- Dimensionless ligand concentration

In the same way, the discretized form of equation (SI-26) is:

$$q_L(z, t + \Delta t) - q_L(z, t) = \left\{ \begin{matrix} \alpha_{L,R} \\ \alpha_L \end{matrix} \right\} [q_L(z + h_i, t + \Delta t) - 2q_L(z, t + \Delta t) + q_L(z - h_i, t + \Delta t)]$$

$$- \Delta t k_a c_M^* q_M(z, t + \Delta t) q_L(z, t + \Delta t) + \Delta t k_d \frac{c_{T,L}^*}{c_L^*} q_{T,L}(z, t + \Delta t) - \Delta t k_d q_L(z, t + \Delta t), \quad (\text{SI-43})$$

or

$$-\left\{ \begin{matrix} \alpha_{L,R} \\ \alpha_L \end{matrix} \right\} q_L(z - h_i, t + \Delta t) + \left[1 + 2 \left\{ \begin{matrix} \alpha_{L,R} \\ \alpha_L \end{matrix} \right\} + \Delta t k_a c_M^* q_M(z, t + \Delta t) + \Delta t k_d \right] q_L(z, t + \Delta t)$$

$$- \left\{ \begin{matrix} \alpha_{L,R} \\ \alpha_L \end{matrix} \right\} q_L(z + h_i, t + \Delta t) = q_L(z, t) + \Delta t k_d \frac{c_{T,L}^*}{c_L^*} q_{T,L}(z, t + \Delta t). \quad (\text{SI-44})$$

Particular equations for each $q_L(z_i, t + \Delta t)$ can be written.

- The first equation, for z_1 reads:

$$q_L(z_2, t + \Delta t) - q_L(z_1, t + \Delta t) = 0.$$

- From $j = 2$ to $n - 1$:

$$\begin{aligned} -\alpha_{L,R} q_L(z_j - h_r, t + \Delta t) + \left[1 + 2\alpha_{L,R} + \Delta t k_a c_M^* q_M(z_j, t + \Delta t) + \Delta t k_d \right] q_L(z_j, t + \Delta t) \\ -\alpha_{L,R} q_L(z_j + h_r, t + \Delta t) = q_L(z_j, t) + \Delta t k_d \frac{c_{T,L}^*}{c_L^*} q_{T,L}(z_j, t + \Delta t). \end{aligned} \quad (SI-46)$$

- At $z = z_n = r^*$:

$$\frac{d_{L,R}}{d_L} \frac{q_L(z_n, t + \Delta t) - q_L(z_{n-1}, t + \Delta t)}{h_r} = \frac{q_L(z_{n+1}, t + \Delta t) - q_L(z_n, t + \Delta t)}{h_g}, \quad (SI-47)$$

which rewrites as

$$-\sigma q_L(z_{n-1}, t + \Delta t) + (\sigma + 1) q_L(z_n, t + \Delta t) - q_L(z_{n+1}, t + \Delta t) = 0. \quad (SI-48)$$

- For $j = n + 1$ to $m - 1$:

$$\begin{aligned} -\alpha_L q_L(z_j - h_g, t + \Delta t) + \left[1 + 2\alpha_L + \Delta t k_a c_M^* q_M(z_j, t + \Delta t) + \Delta t k_d \right] q_L(z_j, t + \Delta t) \\ -\alpha_L q_L(z_j + h_g, t + \Delta t) = q_L(z_j, t) + \Delta t k_d \frac{c_{T,L}^*}{c_L^*} q_{T,L}(z_j, t + \Delta t). \end{aligned} \quad (SI-49)$$

- At $z = z_m = g^*$:

$$q_L(z_m, t + \Delta t) = 1. \quad (SI-50)$$

1.3.4.- Dimensionless metal concentration

Let us define $\alpha_M = \frac{\Delta t}{\Delta x^2}$ and $\alpha_{M,R} = d_{M,R} \alpha_M$.

Discretization of equation (SI-22) becomes:

$$q_M(z_j, t + \Delta t) - q_M(z_j, t) = \alpha_{M,R} \left[q_M(z_j + h_r, t + \Delta t) - 2q_M(z_j, t + \Delta t) + q_M(z_j - h_r, t + \Delta t) \right]$$

$$\begin{aligned}
& -\Delta t k_a c_L^* q_M(z_j, t + \Delta t) q_L(z_j, t + \Delta t) + \Delta t k_d \frac{c_{T,L}^*}{c_M^*} q_{T,L}(z_j, t + \Delta t) - \Delta t k_d \frac{c_L^*}{c_M^*} q_L(z_j, t + \Delta t) \\
& -\Delta t k_{a,R} c_{T,R}^* q_M(z_j, t + \Delta t) q_R(z_j, t + \Delta t) + \Delta t k_{d,R} \frac{c_{T,R}^*}{c_M^*} [1 - q_R(z_j, t + \Delta t)], \tag{SI-51}
\end{aligned}$$

and for equation (SI-23):

$$\begin{aligned}
q_M(z_j, t + \Delta t) - q_M(z_j, t) &= \alpha_M [q_M(z_j + h_g, t + \Delta t) - 2q_M(z_j, t + \Delta t) + q_M(z_j - h_g, t + \Delta t)] \\
& -\Delta t k_a c_L^* q_M(z_j, t + \Delta t) q_L(z_j, t + \Delta t) + \Delta t k_d \frac{c_{T,L}^*}{c_M^*} q_{T,L}(z_j, t + \Delta t) - \Delta t k_d \frac{c_L^*}{c_M^*} q_L(z_j, t + \Delta t). \tag{SI-52}
\end{aligned}$$

The equations for each spatial node can be constructed with the same procedure as before.

- For z_1 :

$$q_M(z_2, t + \Delta t) - q_M(z_1, t + \Delta t) = 0. \tag{SI-53}$$

- From $j = 2$ to $n - 1$:

$$\begin{aligned}
& -\alpha_{MR} q_M(z_j - h_r, t + \Delta t) \\
& + [1 + 2\alpha_{MR} + \Delta t k_a c_L^* q_L(z_j, t + \Delta t) + \Delta t k_{a,R} c_{T,R}^* q_R(z_j, t + \Delta t)] q_M(z_j, t + \Delta t) \\
& -\alpha_{M,R} q_M(z_j + h_r, t + \Delta t) \\
& = q_M(z_j, t) + \Delta t k_d \frac{c_{T,L}^*}{c_M^*} q_{T,L}(z_j, t + \Delta t) - \Delta t k_d \frac{c_L^*}{c_M^*} q_L(z_j, t + \Delta t) + \Delta t k_{d,R} \frac{c_{T,R}^*}{c_M^*} [1 - q_R(z_j, t + \Delta t)]. \tag{SI-54}
\end{aligned}$$

- At $z = z_n = r^*$:

$$d_{M,R} \frac{q_M(z_n, t + \Delta t) - q_M(z_{n-1}, t + \Delta t)}{h_r} = \frac{q_M(z_{n+1}, t + \Delta t) - q_M(z_n, t + \Delta t)}{h_g}. \tag{SI-55}$$

- From $j = n + 1$ to $m - 1$:

$$\begin{aligned}
& -\alpha_M q_M(z_j - h_g, t + \Delta t) + [1 + 2\alpha_M + \Delta t k_a c_L^* q_L(z_j, t + \Delta t)] q_M(z_j, t + \Delta t) - \alpha_M q_M(z_j + h_g, t + \Delta t) \\
& = q_M(z_j, t) + \Delta t k_d \frac{c_{T,L}^*}{c_M^*} q_{T,L}(z_j, t + \Delta t) - \Delta t k_d \frac{c_L^*}{c_M^*} q_L(z_j, t + \Delta t). \tag{SI-56}
\end{aligned}$$

$$q_M(z_m, t + \Delta t) = 1. \quad (\text{SI-57})$$

1.4.- Solution Procedure

The coupled system of non linear equations obtained in the previous section (equations SI-34 to SI-57) will be solved separately for each species and time. The solution is obtained after iteration and convergence of the concentration of each species at each spatial position. This method allows a extremely huge reduction of the computational time in comparison to the CPU time required for the direct solution of the non-linear system. Let us comment in more detail on the solution procedure.

The solution process begins by initializing the $m + n$ components of vectors $\vec{q}_{T,L}, \vec{q}_L, \vec{q}_M$ and $\vec{q}_R$ with the values reached at the previous time interval. The values of vectors $\vec{q}_{T,L}, \vec{q}_L, \vec{q}_M$ and $\vec{q}_R$ at $t + \Delta t$ are obtained iteratively. For $q_L(z_i, t + \Delta t)$, for example, the equations system (SI-45)-(SI-50) could be rewritten in a matrix form as,

$$= \begin{pmatrix} 0 \\ q_L(z_2, t) + \Delta tk_d \frac{c_{TL}^+}{C_L^-} q_{TL}(z_2, t + \Delta t) \\ \vdots \\ q_L(z_j, t) + \Delta tk_d \frac{c_{TL}^+}{C_L^-} q_{TL}(z_j, t + \Delta t) \\ \vdots \\ 0 \\ \vdots \\ q_L(z_j, t) + \Delta tk_d \frac{c_{TL}^+}{C_L^-} q_{TL}(z_j, t + \Delta t) \\ \vdots \\ 1 \end{pmatrix}$$

This is a tridiagonal system for the unknowns $q_L(z_i, t + \Delta t)$ and it is solved iteratively through the TRIDAG.FOR subroutine (Press et al. 1986). Notice that this equation system for q_L , requires the values of $q_M(z_i, t + \Delta t)$ and $q_{T,L}(z_i, t + \Delta t)$ which are also unknowns. At iteration j , to uncouple $(q_M)_j$ and $(q_{T,L})_j$ from $(q_L)_j$, we use the values of both $(q_M(z_i, t + \Delta t))_{j-1}$ and $(q_{T,L}(z_i, t + \Delta t))_{j-1}$ obtained in the previous iteration ($j-1$) in the solution of $q_L(z_i, t + \Delta t)$ at some iteration j . This procedure is applied iteratively for each species until all the system converges to a solution for each time step. The time is then increased and the first iteration for the next time starts initializing all the unknowns with the values obtained at the previous time.

Figure SI-3 shows schematically the algorithm used to solve the system

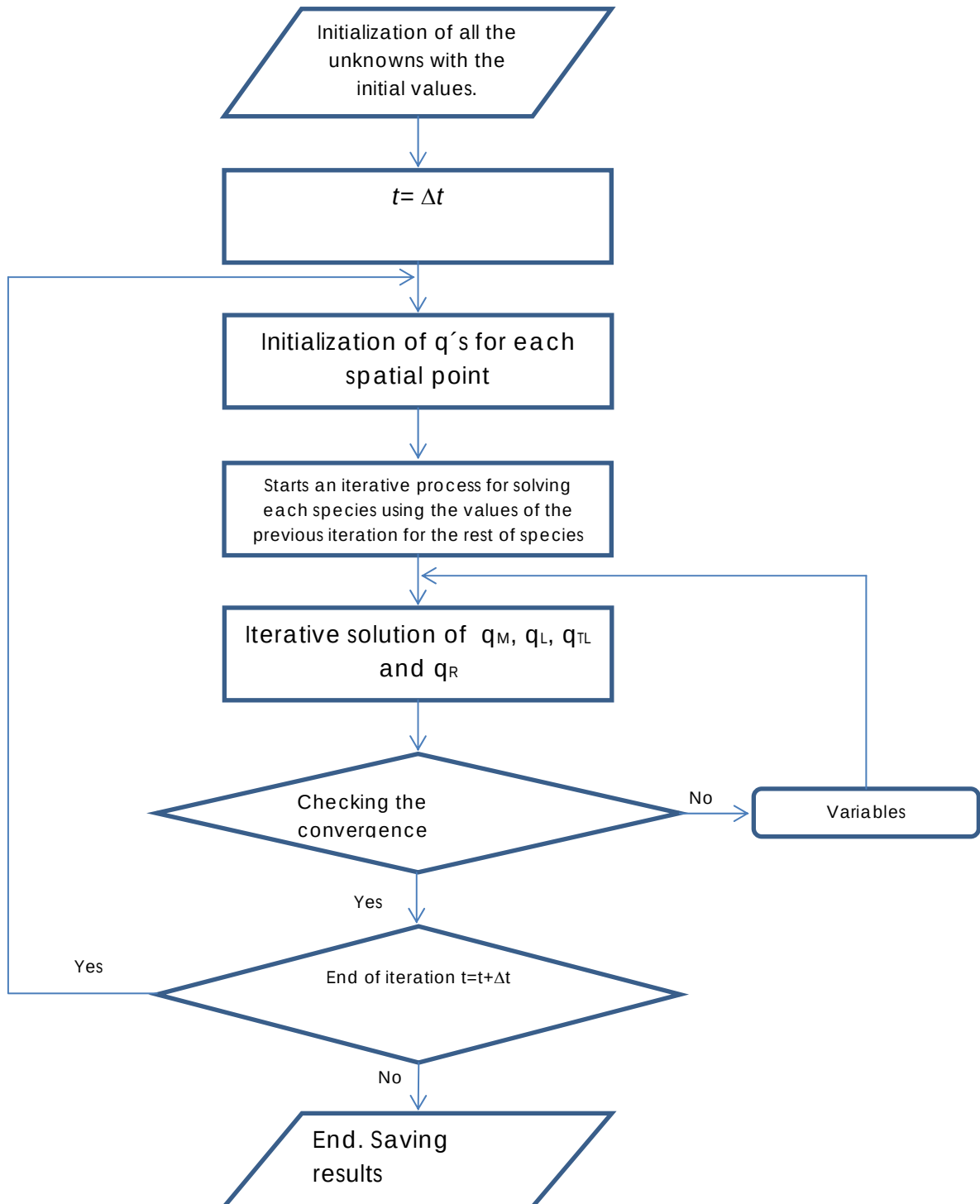


Figure SI-4. Flux diagram representing the algorithm used to solve the system

2.- Concentration profiles in a DGT experiment

Let us consider a DGT experiment using the numerical simulation described above. Fig. SI-5 depicts the concentration profiles of metal and complex through the DGT layers

and adjoining solution for different values of the kinetic complexation constants. With the parameters used in this figure, the metal concentration drops to almost zero at the resin interface due to the strong and fast resin binding. For low values of the dissociation rate constants (see panel a), the complex concentration profile is flat and equal to the complex concentration in solution, while the metal concentration profile is linear. This indicates the inert behaviour of the complex, which does not contribute to the flux received by DGT and the quasi-steady-state regime reached (the linear metal concentration profile indicates a time independent metal flux). On increasing the kinetic complexation constants (see panel b), the complex is depleted and its contribution to the metal flux through dissociation is apparent. Notice that the metal concentrations do not increase linearly with distance and their values at a given x are greater than those of the inert case, due to the complex dissociation contributing to a higher local metal concentration. A further increase of the kinetic constants leads to a more depleted complex concentration profile. Metal and complex concentration profiles increasingly coincide in the gel domain (see panel c). When both normalised profiles coincide, metal and complex are in local equilibrium, indicating that the complex is able to dissociate sufficiently rapidly to maintain equilibrium conditions with the metal. The thickness of the layer where both profiles diverge, can be related to the reaction layer. As expected, the thickness of the reaction layer decreases as the kinetic constants increase. Notice that at the interface between the resin and gel layers the slope of the complex concentration profile is not zero and the complex penetrates into the resin layer. The decrease in the complex concentration as the back plastic wall of the device is approached continues inside the resin, indicating that the dissociation process does not cease at the resin interface. A further increase of the kinetic constants (see panel d) leads to linear metal and complex concentration profiles superimposed throughout the entire

gel domain. This corresponds to the labile situation where the dissociation of the complex is so fast that local equilibrium with the metal is reached at each relevant spatial and time position.

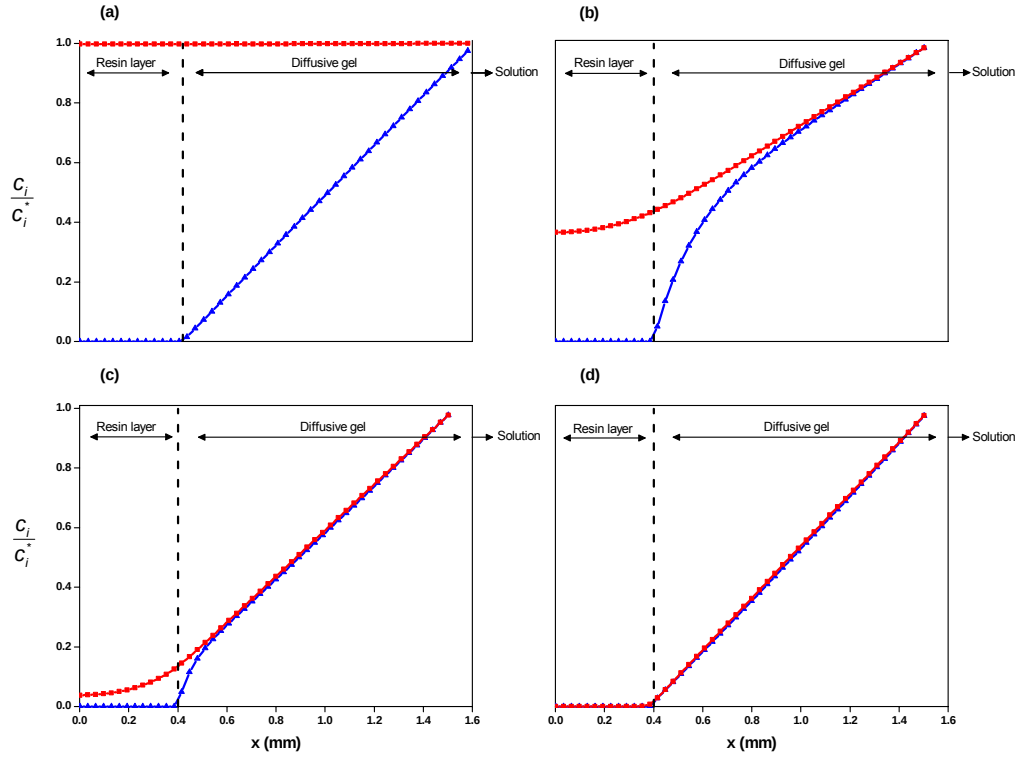


Figure SI-5. Normalized concentration profiles of M (Blue line with ▲ markers) and ML (red line with ■ markers). Profiles are obtained by numerical simulation described in SI-1. Parameters: $r = 4 \times 10^{-4} \text{ m}$, $K = 10^2 \text{ mol}^{-1} \text{ m}^3 \text{ s}^{-1}$, panel a): $k_d = 10^{-6} \text{ s}^{-1}$, panel b) $k_d = 10^{-3} \text{ s}^{-1}$, panel c) $k_d = 10^{-2} \text{ s}^{-1}$ and panel d) $k_d = 10^0 \text{ s}^{-1}$. The rest of parameters as in figure 1 of the manuscript.

3.- Experimental Section

- DGT sensors

All DGT sensors were purchased from DGT Research Ltd. (Lancaster, U.K.). Commercially available DGT deployment mouldings made of ABS polymer, based on a simple, tight-fitting piston design with a 2 cm diameter window, were used for all

measurements. A 0.4 mm thick Chelex-gel was placed on the piston surface with the side packed with resin beads facing upward (i.e. in close contact with the diffusive layer). On the top of the Chelex-gel, a 0.8 mm thick diffusive agarose polyacrylamide gel and a cellulose nitrate membrane (Whatman, pore size 0.45 μm , thickness 0.125 mm) were placed. A more detailed description is found at DGT Research's homepage (<http://www.dgtresearch.com>).

- DGT Experiments

A series of experiments were performed to determine the mass of cadmium accumulated at different times by DGT devices deployed in solutions containing Cd (prepared from the solid nitrate product, Merck, analytical grade) at a concentration close to $10^{-2} \text{ mol m}^{-3}$ and NTA (Fluka, analytical grade) at concentrations of 0.249 and 1.8 mol m^{-3} . pH was adjusted by means of small additions of NaOH or HNO_3 to 7 or 7.5 before and during the deployment. Ionic strength of the solution was adjusted to 0.05 mol L^{-1} with NaNO_3 (Merck, suprapur). Ultra-pure water (Mill-Q plus 185 System, Millipore) was employed in all the experiments.

- DGT Exposure Chamber

A 5L polyethylene bucket was used as the exposure chamber. 11 DGTs were fixed by press-stud. pH was monitored continuously with a glass electrode. A reference electrode $\text{Ag/AgCl}/3 \text{ mol.L}^{-1} \text{ KCl}$, with a $0.05 \text{ mol.L}^{-1} \text{ NaNO}_3$ jacket was used. The exposure chamber was placed in a thermostated bath to keep the deployment solution at constant temperature of $25 \pm 0.1^\circ\text{C}$. The solution was stirred during deployment using an overhead stirrer.

- Retrieval and analysis

For all experiments, aliquots of the solution were collected at regular intervals to check the total Cd concentration. DGT devices, once removed from solution, were rinsed with

ultrapure water and opened for removal of the resin gels, which were then eluted in 1mL of concentrated nitric acid for at least 24h. The number of moles of metal in the form of non dissociated complex due to the complex penetration into the resin domain is negligible in comparison with those bound to the resin beads. All solutions were analysed by inductively coupled plasma-optical emission spectroscopy (ICP-OES) (Activa-S, Horiba Scientific).

4.- Additional figures

Additional figures that verified the influence of the thickness of the DGT resin layer on the accumulated mass for the Cd-NTA system.

Conditional stability constants and kinetic parameters for the Cd NTA system at a given pH, ionic strength and total metal and total ligand concentration were estimated as reported in the manuscript. Values used in the numerical simulations for the kinetic association and dissociation constants of the metal to the resin sites are $k_{a,R} = 10^{15} \text{ mol}^{-1} \text{ m}^3 \text{ s}^{-1}$ and $k_{d,R} = 10^{-6} \text{ s}^{-1}$ while the total concentration of resin sites in the resin layer is $c_{T,R} = 50 \text{ mol m}^{-3}$. These values are high enough to neglect saturation effects and to reach an almost null metal concentration at the resin interface.

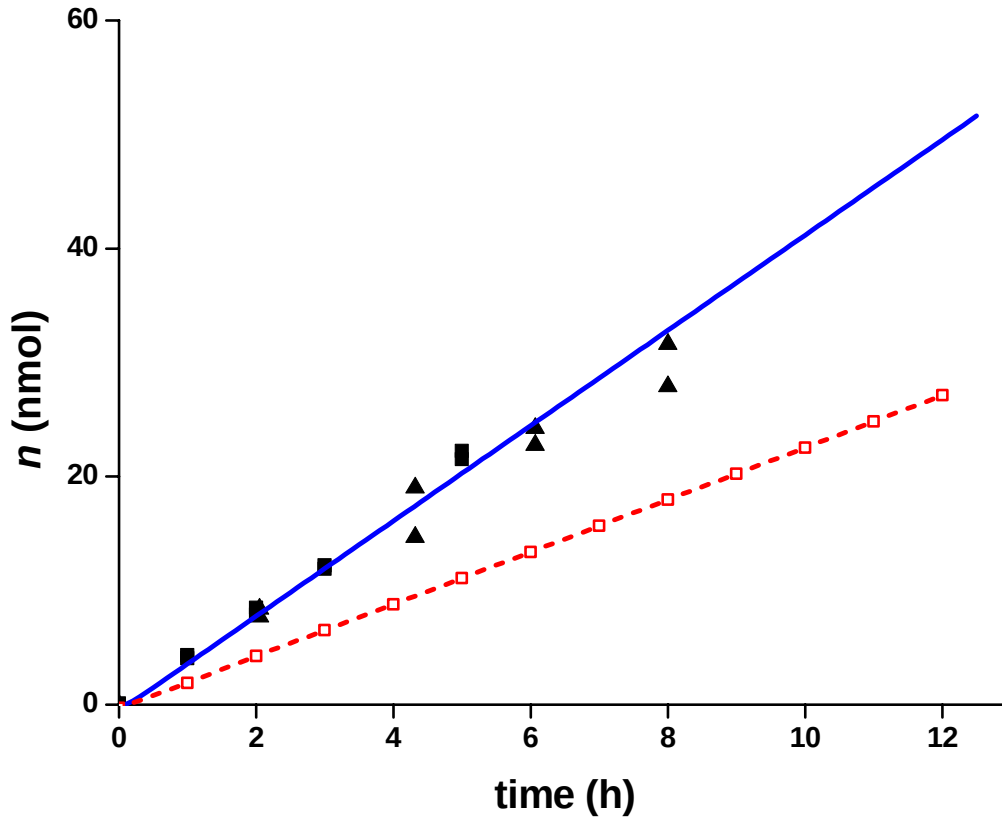


Figure SI-6. Moles of Cd accumulated by DGT in presence of NTA. Markers: experimental measurements, two deployments (■) and (▲). Blue continuous line: theoretical accumulation predicted by numerical simulation when penetration of the complex into the resin layer is considered ($r = 4 \times 10^{-4} \text{ m}$). Red dashed line with markers □: theoretical accumulation predicted by numerical simulation when penetration of the complex into the resin layer is not allowed ($r = 0$). Parameters: total NTA concentration $c_{\text{T,NTA}} = 0.249 \text{ mol m}^{-3}$, total Cd concentration $c_{\text{T,Cd}} = 9.96 \times 10^{-3} \text{ mol m}^{-3}$, $\text{pH} = 7.03$, $I = 0.05 \text{ M}$, $k_a^{\text{eff}} = 8.77 \times 10^4 \text{ m}^3 \text{ mol}^{-1} \text{ s}^{-1}$ and $k_d = k_d^{\text{eff}} = \frac{k_a^{\text{eff}}}{K_{\text{CdNTA}}^{\text{eff}}} = 2.76 \text{ s}^{-1}$. The rest of parameters as in figure 4 of the manuscript.

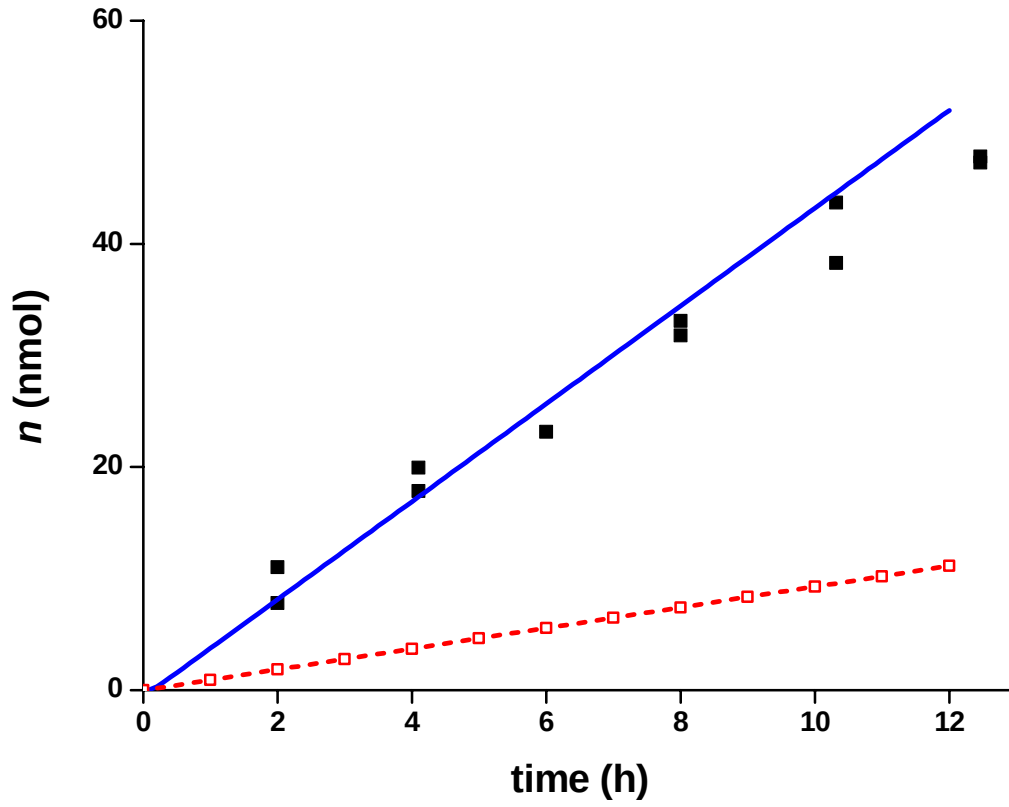


Figure SI-7. Moles of Cd accumulated by DGT in presence of NTA. Marker (■): experimental measurements. Blue continuous line: theoretical accumulation predicted by numerical simulation when penetration of the complex into the resin layer is considered ($r = 4 \times 10^{-4} \text{ m}$). Red line with markers □: theoretical accumulation predicted by numerical simulation when penetration of the complex into the resin layer is not allowed ($r = 0$). Parameters: total NTA concentration $c_{\text{T,NTA}} = 1.8 \text{ mol m}^{-3}$, total Cd concentration $c_{\text{T,Cd}} = 1.08 \times 10^{-2} \text{ mol m}^{-3}$, pH=7.50, ionic strength 0.05M,

$k_a^{\text{eff}} = 2.58 \times 10^5 \text{ m}^3 \text{ mol}^{-1} \text{ s}^{-1}$ and $k_d = k_d^{\text{eff}} = \frac{k_a^{\text{eff}}}{K_{\text{CdNTA}}^{\text{eff}}} = 2.76 \text{ s}^{-1}$. The rest of parameters as in figure 4 of the manuscript.

5.- Formulation of the Cd-NTA speciation in a DGT sensor as a system with only one complex and ligand species.

NTA is involved in four acid-base equilibria. Among all these species only NTA^{3-} is known to interact with Cd to give the complex species CdNTA and Cd(NTA)_2 . Thus only NTA^{3-} is the ligand in the Cd-NTA system. However, the concentration of NTA^{3-} is not only modified by the presence of Cd, but also by the pH of the system. The formulation of the Cd-NTA system as



with a fixed total ligand concentration, $c_{\text{T,L}}$, computed as $c_{\text{T,L}} = c_{\text{L}} + c_{\text{M,L}}$ is then not valid. It is the aim of this section of this supporting information to show that the Cd-NTA system can be reformulated so that equations equivalent to the system represented with scheme SI-60 can be applied.

Let us assume that

- i) protonated and unprotonated NTA species have the same diffusion coefficient, D_{L}
- ii) the kinetics of interconversion between the protonated/unprotonated NTA species is considered instantaneous (i.e. they are always at equilibrium), so that all the protonated and unprotonated species diffuse and react as one “single species”.

A scheme of the processes in solution is:



The transport problem can be stated as

$$\frac{\partial c_{\text{M}}}{\partial t} = D_{\text{M}} \frac{\partial^2 c_{\text{M}}}{\partial x^2} + k_{\text{d,L}} c_{\text{ML}} - k_{\text{a,L}} c_{\text{M}} c_{\text{L}} \tag{SI-61}$$

$$\frac{\partial c_{\text{ML}}}{\partial t} = D_{\text{L}} \frac{\partial^2 c_{\text{ML}}}{\partial x^2} - k_{\text{d,L}} c_{\text{ML}} + k_{\text{a,L}} c_{\text{M}} c_{\text{L}} \tag{SI-62}$$

$$\frac{\partial c_{\text{L}}}{\partial t} = D_{\text{L}} \frac{\partial^2 c_{\text{L}}}{\partial x^2} + k_{\text{d,L}} c_{\text{ML}} - k_{\text{a,L}} c_{\text{M}} c_{\text{L}} + k_{\text{d1,H}} c_{\text{HL}} - k_{\text{a1,H}} c_{\text{H}} c_{\text{L}} \tag{SI-63}$$

$$\frac{\partial c_{\text{HL}}}{\partial t} = D_{\text{L}} \frac{\partial^2 c_{\text{HL}}}{\partial x^2} + k_{\text{d2,H}} c_{\text{H}_2\text{L}} - k_{\text{a2,H}} c_{\text{H}} c_{\text{HL}} - k_{\text{d1,H}} c_{\text{HL}} + k_{\text{a1,H}} c_{\text{H}} c_{\text{L}} \tag{SI-64}$$

....

$$\frac{\partial c_{\text{H}_4\text{L}}}{\partial t} = D_{\text{L}} \frac{\partial^2 c_{\text{H}_4\text{L}}}{\partial x^2} - k_{\text{d4,H}} c_{\text{H}_3\text{L}} + k_{\text{a4,H}} c_{\text{H}} c_{\text{H}_3\text{L}} \tag{SI-65}$$

Adding the transport Eqns. of all the protonated ligand forms (Eqns. (SI-63)-(SI-65))

$$\frac{\partial c_{\text{L,P}}}{\partial t} = D_{\text{L}} \frac{\partial^2 c_{\text{L,P}}}{\partial x^2} + k_{\text{d,L}} c_{\text{ML}} - k_{\text{a,L}} c_{\text{M}} c_{\text{L}} \tag{SI-66}$$

where $c_{\text{L,P}}$ stands for

$$c_{\text{L,P}} = c_{\text{L}} + c_{\text{HL}} + c_{\text{H}_2\text{L}} + c_{\text{H}_3\text{L}} + c_{\text{H}_4\text{L}} \tag{SI-67}$$

Since protonation is instantaneous, acid-base equilibria relationship apply:

$$\beta_{i,\text{H}} = \frac{c_{\text{H}_i\text{L}}}{c_{\text{H}}^i c_{\text{L}}} \tag{SI-68}$$

c_{L} can be rewritten as

$$c_L = \frac{c_{L,P}}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} \quad (\text{SI-69})$$

In terms of $c_{L,P}$, Eqns. (SI-61), (SI-62) and (SI-66) become

$$\frac{\partial c_M}{\partial t} = D_M \frac{\partial^2 c_M}{\partial x^2} + k_{d,L} c_{ML} - \frac{k_{a,L}}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} c_M c_{L,P} \quad (\text{SI-70})$$

$$\frac{\partial c_{ML}}{\partial t} = D_L \frac{\partial^2 c_{ML}}{\partial x^2} - k_{d,L} c_{ML} + \frac{k_{a,L}}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} c_M c_{L,P} \quad (\text{SI-71})$$

and

$$\frac{\partial c_{L,P}}{\partial t} = D_L \frac{\partial^2 c_{L,P}}{\partial x^2} + k_{d,L} c_{ML} - \frac{k_{a,L}}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} c_M c_{L,P} \quad (\text{SI-72})$$

Eqns. (SI-70)-(SI-72) are formally identical to a system with one ligand with concentration $c_{L,P}$, that is not involved in any protonation equilibria. The effective association and dissociation constants of this ligand with the metal are

$$k_d^{\text{eff}} = k_{d,L} \quad (\text{SI-73})$$

and

$$k_a^{\text{eff}} = \frac{k_{a,L}}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} \quad (\text{SI-74})$$

The effective stability constant of the metal complexation with this formal ligand $c_{L,P}$, of concentration given by Eqn (SI-67), is

$$K^{\text{eff}} = \frac{k_a^{\text{eff}}}{k_d^{\text{eff}}} = \frac{K}{1 + \sum_{i=1}^4 \beta_{i,H} c_H^i} \quad (\text{SI-75})$$

6.- Parameter values in all the figures of the manuscript

Table SI-1

Parameter		Fig. 1	Fig. 2	Fig. 3	Fig. 4	Units
Resin thickness	r			4×10^{-4}		m
Gel thickness	g	1.13×10^{-3}	1.13×10^{-3}		1.13×10^{-3}	m
Stability constant	K	10^2	10^2		10^2	$\text{mol}^{-1} \text{m}^3$
Association rate constant between M and L	k_a		10^{-1}		2.58×10^5	$\text{mol}^{-1} \text{m}^3 \text{s}^{-1}$
Dissociation rate constant between M and L	k_d		10^{-3}		2.76	s^{-1}
Association rate constant between M and R	$k_{a,R}$	10^{15}	10^{15}	10^{15}	10^{15}	$\text{mol}^{-1} \text{m}^3 \text{s}^{-1}$
Dissociation rate constant between M and R	$k_{d,R}$	10^{-6}	10^{-6}	10^{-6}	10^{-6}	s^{-1}
Diffusion coefficient of M in resin and gel	D_M $D_{M,R}$	6.09×10^{-10}	6.09×10^{-10}	6.09×10^{-10}	6.09×10^{-10}	$\text{m}^2 \text{s}^{-1}$
Diffusion coefficient of L in the resin and gel domains	D_L $D_{L,R}$	4.26×10^{-10} $D_{L,R}=D_L$	4.26×10^{-10} $D_{L,R}=D_L$		4.26×10^{-10} $D_{L,R}=D_L$	$\text{m}^2 \text{s}^{-1}$
Diffusion coefficients of ML in resin and gel	D_{ML} $D_{ML,R}$	4.26×10^{-10} $D_{ML,R}=D_{ML}$	4.26×10^{-10}		4.26×10^{-10}	$\text{m}^2 \text{s}^{-1}$
Total concentration of M	$C_{T,M}$	0.01	0.01		1.08×10^{-2}	mol m^{-3}

Total concentration of L	$C_{T,L}$	0.249	0.249		0.249	mol m ⁻³
Total concentration of R	$C_{T,R}$	50	50	50	50	mol m ⁻³
Ionic strength	I			0.05	50	M
pH					7.50	

All simulations in this manuscript were calculated with a spatial grid of 2000 points and a time interval $\Delta t = 0.1$ s.

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